Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Height:	
1.940 inches	
End Application:	
C-5m	
Voltage Rating In Volts Per Characteristic:	
64.6 breakdown voltage, instantaneous	
Power Rating Per Characteristic:	
1500.00 watts peak pulse output power	
Maximum Operating Tempurature Per Measurement Point:	
-65.00 degrees celsius ambient air and 175.00 degrees celsius ambient air	
Product Name:	
Diode, apu circuit	
Special Features:	
Reverse stand-off volatage: 51.7v, reverse leakage current: 5, breakdown voltage: 64.6v, test current: 20, maximum clamping vol	tage:
97.1, peak pulse current: 15.4, temperature coefficient: 0.100, maximum reverse leakage current: 400	
Special Test Features:	
Peak pulse power: 1500 watts, operating temperature: -65 to 175c, storage temperature: -65 to 175c, steady-state power dissipatio	n @ tl
= 75c (3/8"): 5 watts	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	

No

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